Features

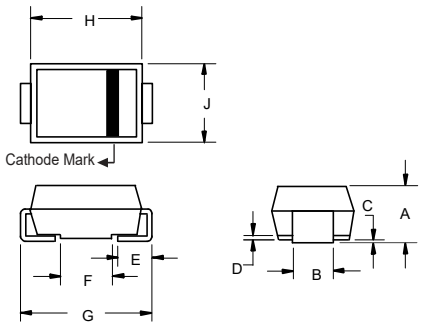
- Halogen Free. "Green" Device (Note 1)
- Glass Passivated Chip Junction
- Super Fast Recovery Time for High Efficiency
- For Surface Mount Applications
- Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1
- Lead Free Finish/RoHS Compliant (Note 2)("P" Suffix Designates RoHS Compliant. See Ordering Information)

1 Amp
Ultra Fast Rectifier
1200 Volts

Maximum Ratings @ 25°C (Unless Otherwise Specified)

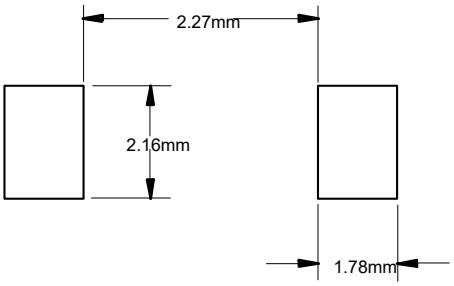
Parameter	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	1200	V
Working Peak Reverse Voltage	V_{RWM}		
DC Blocking Voltage	V_R		
RMS Reverse Voltage	V_{RMS}	840	V
Average Rectified Forward Current @ T_L=110°C	$I_{F(AV)}$	1	A
Non−Repetitive Peak Surge Current @8.3ms Half Sine Wave	I_{FSM}	30	A
Non−Repetitive Peak Surge Current @1ms Square Wave		60	
Current Squared Time @ 1ms≤t≤8.3ms	I^2t	3.735	A^2s

SMA (DO-214AC)



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.075	0.096	1.90	2.44	
B	0.050	0.064	1.27	1.63	
C	0.002	0.008	0.051	0.203	
D	---	0.020	---	0.51	
E	0.030	0.060	0.76	1.52	
F	0.065	0.091	1.65	2.32	
G	0.189	0.220	4.80	5.59	
H	0.157	0.187	4.00	4.75	
J	0.090	0.115	2.25	2.92	

SUGGESTED SOLDER PAD LAYOUT



Internal Structure

Pin	Description	Simplified Outline	Graphic Symbol
1	Cathode		
2	Anode		

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

2. High Temperature Solder Exemption Applied, see EU Directive Annex 7a.

Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_J	Operating Junction Temperature Range		-55		150	°C
T_{stg}	Storage Temperature Range		-55		150	°C
$Rth_{(J-L)}$	Thermal Resistance from Junction to Lead	Note 1		25		°C/W
$Rth_{(J-A)}$	Thermal Resistance from Junction to Ambient	Note 1		75		°C/W

Note:
1.Mounted on P.C.B. with 5mm*5mm copper pad areas.

Electrical Characteristics @ 25°C Unless Otherwise Specified

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Forward Voltage	V_F	I_F=1A;T_J=25°C			1.90	V
Reverse Current	I_R	at Rated V_R;T_J=25°C at Rated V_R;T_J=125°C			5 100	uA
Reverse Recovery Time	t_{rr}	I_F=0.5A; I_R=1.0A; I_{rr}=0.25A;T_J=25°C			75	nS
Junction Capacitance	C_J	V_R=4V;f=1MHz;T_J=25°C		8		pF

Curve Characteristics

Fig. 1 - Forward Current Derating Curve

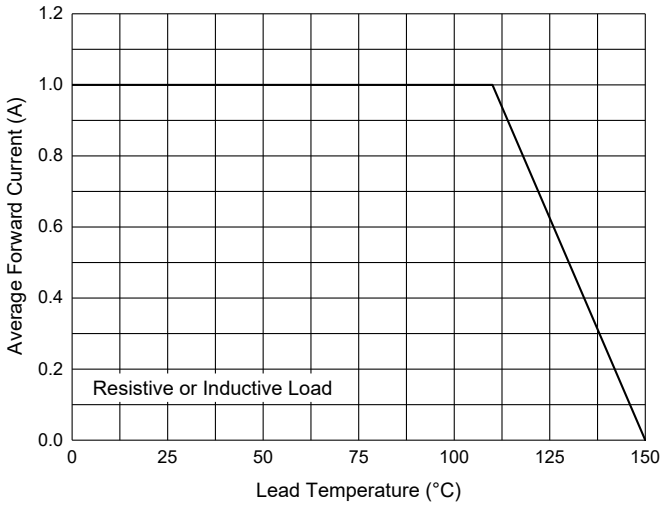


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

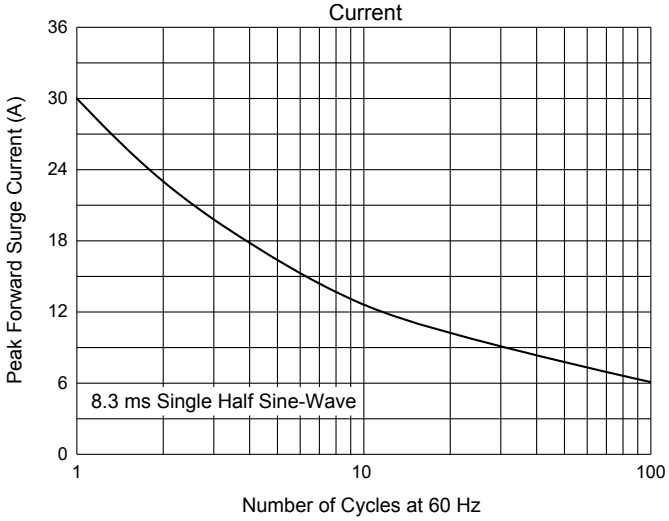


Fig. 3 - Typical Forward Characteristics

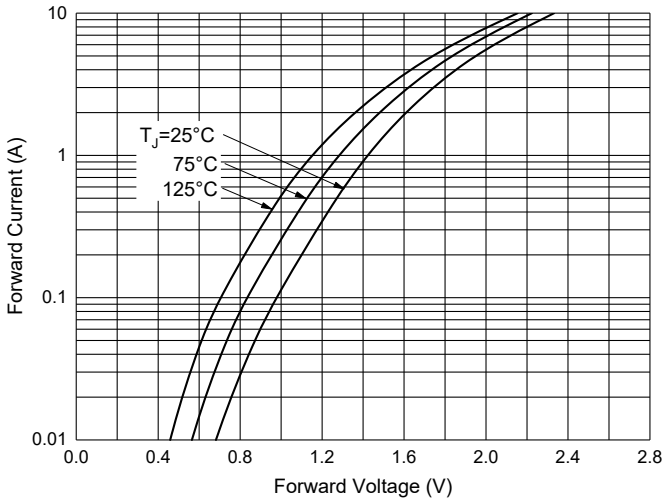


Fig. 4 - Typical Reverse Leakage Characteristics

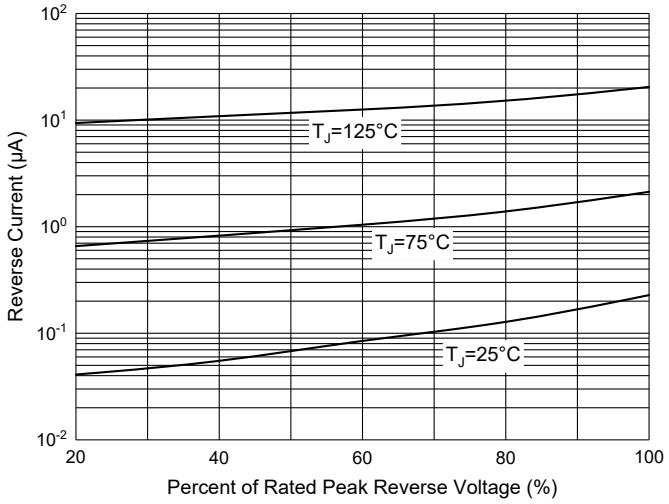
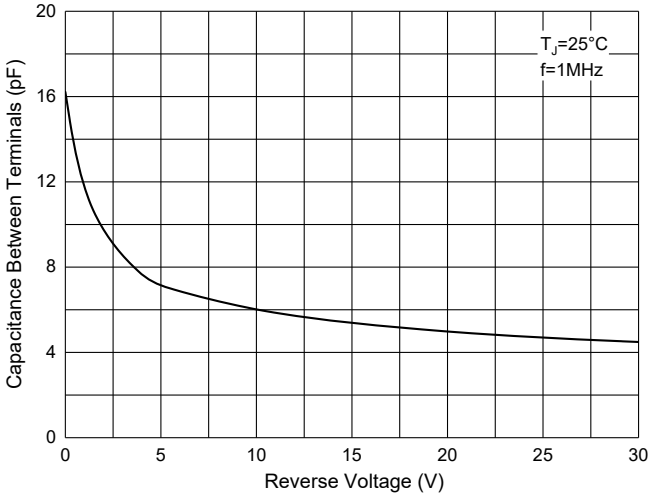


Fig. 5 - Typical Capacitance Characteristics



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel:5Kpcs/Reel